



PJA3433

30V P-Channel Enhancement Mode MOSFET – ESD Protected

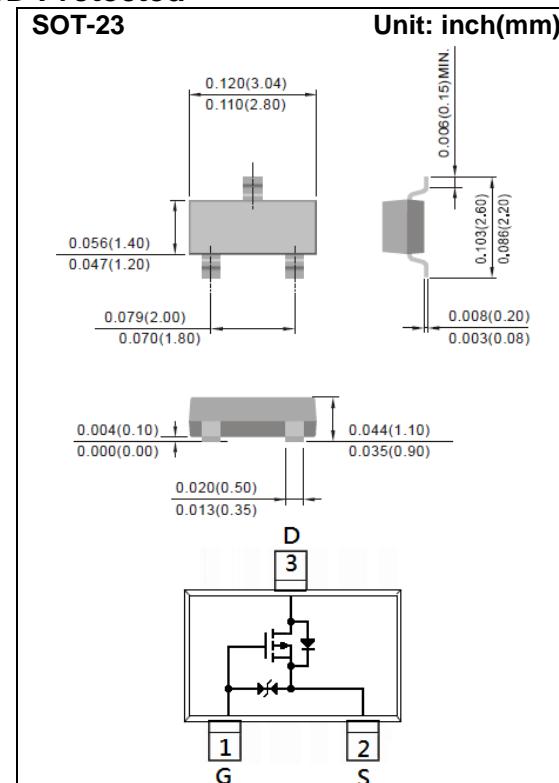
Voltage -30 V Current -1.1A

Features

- RDS(ON) , VGS@-4.5V, ID@-1.1A<370mΩ
- RDS(ON) , VGS@-2.5V, ID@-0.5A<540mΩ
- RDS(ON) , VGS@-2.5V, ID@-0.1A<970mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.
(Halogen Free)

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams
- Marking : A33



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 8	V
Continuous Drain Current	I_D	-1.1	A
Pulsed Drain Current ^(Note 4)	I_{DM}	-4.4	A
Power Dissipation	$T_a=25^\circ\text{C}$	1.25	W
	Derate above 25°C	10	mW/°C
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient ^(Note 3)	$R_{\theta JA}$	100	°C/W



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.5	-0.98	-1.3	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-1.1A$	-	293	370	$m\Omega$
		$V_{GS}=-2.5V, I_D=-0.5A$	-	387	540	
		$V_{GS}=-1.8V, I_D=-0.1A$	-	750	970	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V$	-	-0.01	-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	± 3.4	± 10	μA
Dynamic <small>(Note 5)</small>						
Total Gate Charge	Q_g	$V_{DS}=-15V, I_D=-1.1A,$ $V_{GS}=-4.5V$ <small>(Note 1,2)</small>	-	1.6	-	nC
Gate-Source Charge	Q_{gs}		-	0.5	-	
Gate-Drain Charge	Q_{gd}		-	0.3	-	
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V,$ $f=1.0MHz$	-	125	-	pF
Output Capacitance	C_{oss}		-	22	-	
Reverse Transfer Capacitance	C_{rss}		-	6	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-1.1A,$ $V_{GS}=-4.5V,$ $R_G=6\Omega$ <small>(Note 1,2)</small>	-	11	-	ns
Turn-On Rise Time	t_r		-	51	-	
Turn-Off Delay Time	$t_{d(off)}$		-	65	-	
Turn-Off Fall Time	t_f		-	46	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	-1.0	A
Diode Forward Voltage	V_{SD}	$I_s=-1.0A, V_{GS}=0V$	-	-0.9	-1.2	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{QJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

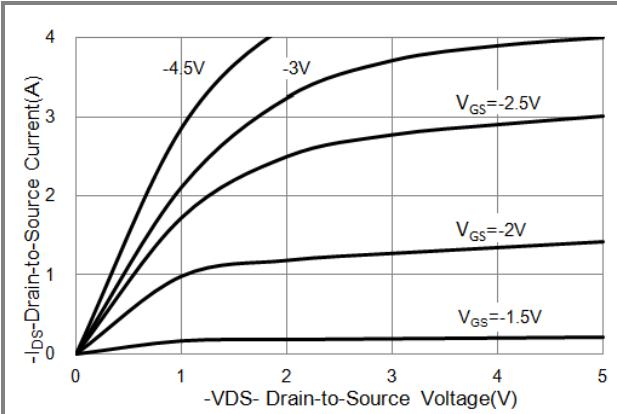


Fig.1 On-Region Characteristics

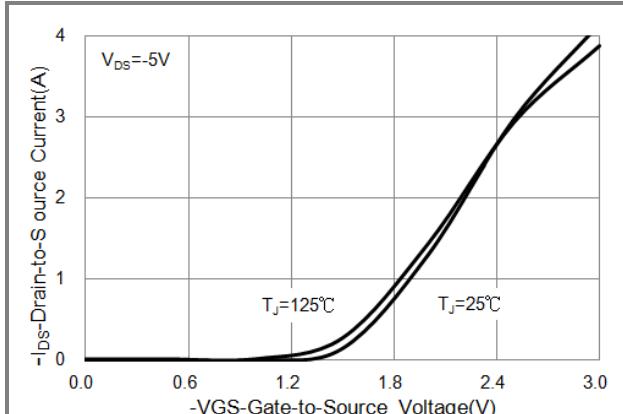


Fig.2 Transfer Characteristics

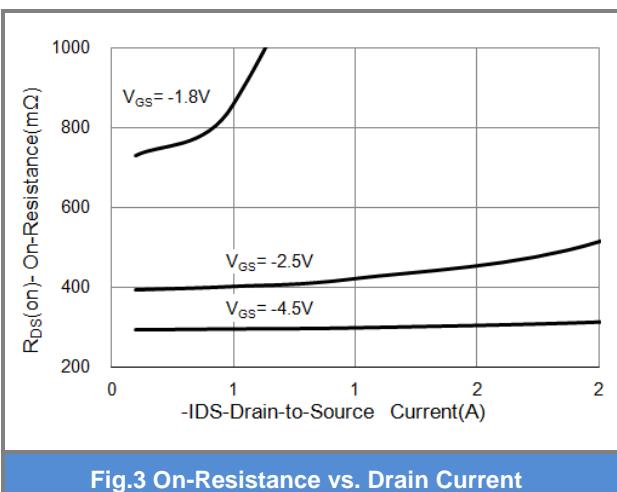


Fig.3 On-Resistance vs. Drain Current

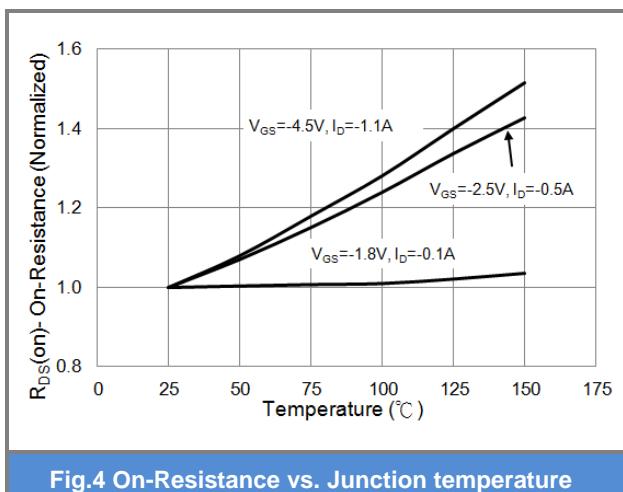


Fig.4 On-Resistance vs. Junction temperature

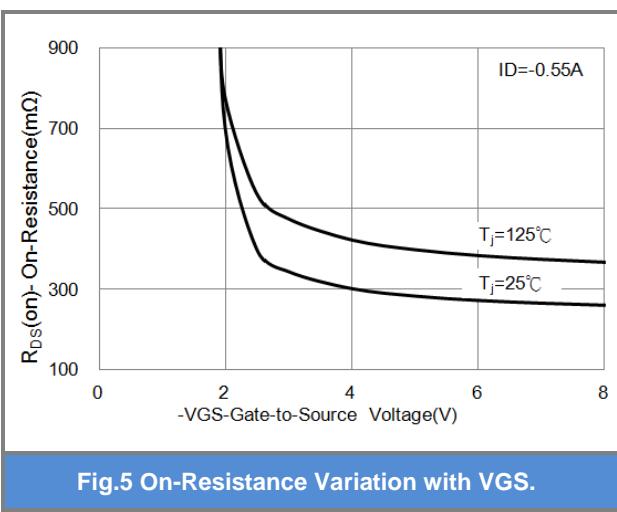


Fig.5 On-Resistance Variation with VGS.

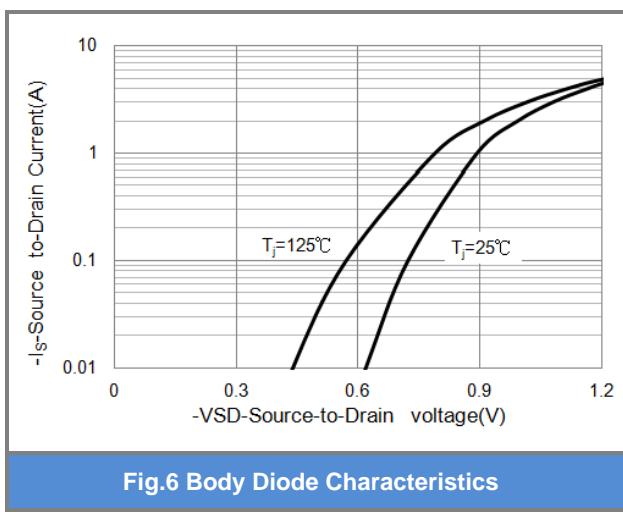


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

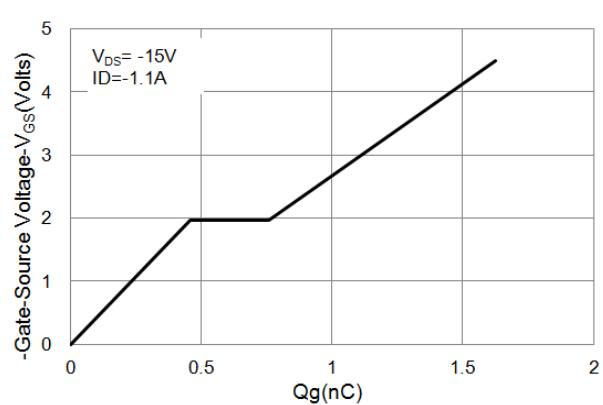


Fig.7 Gate-Charge Characteristics

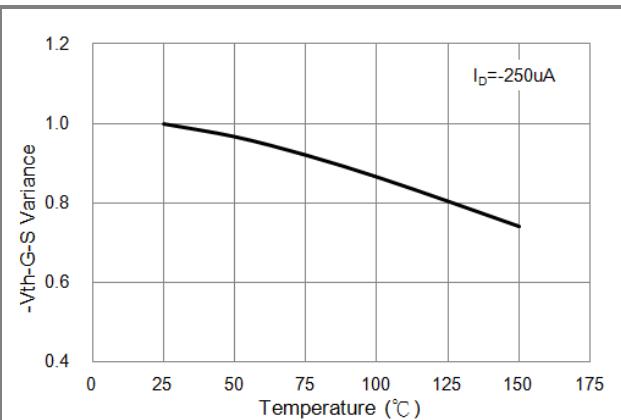


Fig.8 Threshold Voltage Variation with Temperature.

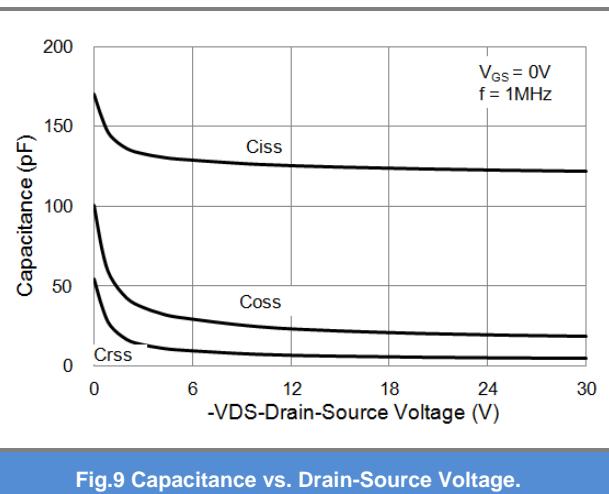


Fig.9 Capacitance vs. Drain-Source Voltage.

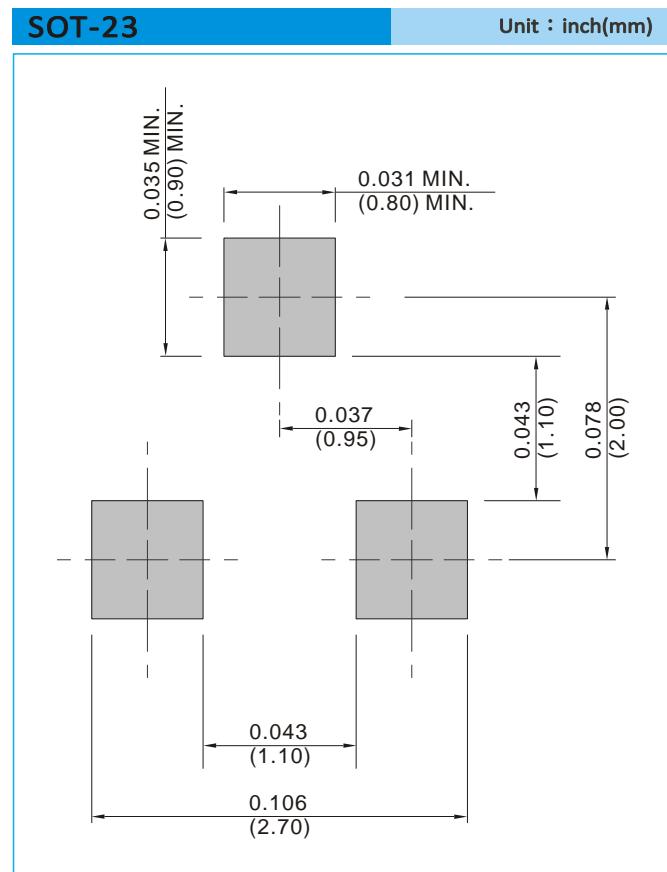


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PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJA3433_R1_00001	SOT-23	3K pcs / 7" reel	A33	Halogen free
PJA3433_R2_00001	SOT-23	12K pcs / 13" reel	A33	Halogen free

MOUNTING PAD LAYOUT





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